DMEM rise time improvements and coldbox results

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Overview

- Comparison of the electronic response and performance of the DMEM board (HD-membrane) equipped with the original amplifier and a new one
- Analysis of data taken in Bicocca laboratories (LN2)
- And at the VD Coldbox (LAr)

Previous works (April Coldbox) here:

https://indico.fnal.gov/event/64355/ and https://indico.fnal.gov/event/64586/ (Federico'spresentations)



Modifications



Component	Original	Modified
<i>R</i> 14	1Ω	3Ω
С9	10nF	3nF
<i>C</i> 17	150 pF	68 <i>pF</i>
<i>C</i> 18	150 <i>pF</i>	68 <i>pF</i>



Rise time





 $SNR - V_{BIAS} = 31.5V$





 $SNR - V_{BIAS} = 32.5V$





"Old ampl" = Original amplifier @ April Coldbox "New ampl" = Modified amplifier @ June Coldbox



52 tick integration window for "Old ampl"21 tick integration window for "New ampl"Cannot use the same for the different rise/fall times





Comparison @ 0.7 VGAIN

Noise FFT of the modified amplifier for different VGAIN in Daphne

Where we gain in terms of RMS and SNR









Win 20 = applying a 20 tick moving window

This decreases a lot the amplitude of a fast signal \rightarrow The old-amplifier signal had more benefits from this filter







FFT headache :)

SPE: average FFT of SPE-waveform candidates Average SPE: FFT of the average SPE-waveform



Conclusions

- The modifications lead to a faster rise time ($133 \rightarrow 81 \text{ ns}$)
- The SNR improved in the range of interest (around 1500 p.e.)
- A faster signal is less afffected by the attenuation (VGAIN) in Daphne
- The FFTs explain where the improvements come from



Backup







Slide from April coldbox analysis

For all the analyses I requred that all the ticks in the pretrigger fall in the [-1.5 spe ampl;+ 1.5 spe ampl] range An example from MiB data with VGAIN 0.7:

- DR 1'400 p.e. SPE ampl 8.9 ADC SPE undershoot 3 ADC
- SNR: integral = 4.7 RMS = 2.3 RMS moving average = 4.6



Backup



